

Vishay General Semiconductor

COMPLIANT

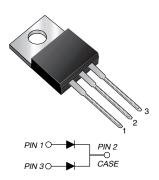
HALOGEN

**FREE** 

# **Dual High-Voltage Trench MOS Barrier Schottky Rectifier**

# TMBS<sup>®</sup>

**TO-220AB** 



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 5.0 A			
$V_{RRM}$	90 V, 100 V			
I <sub>FSM</sub>	120 A			
V <sub>F</sub>	0.75 V			
T <sub>J</sub> max.	150 °C			
Package	TO-220AB			
Diode variation	Dual common cathode			

#### **FEATURES**

- Trench MOS Schottky technology
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application

#### **MECHANICAL DATA**

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	MBR1090CT	MBR10100CT	UNIT
Maximum repetitive peak reverse voltage		$V_{RRM}$	90	100	V
Maximum peak reverse voltage		$V_{RWM}$	90	100	V
Maximum DC blocking voltage		$V_{DC}$	90	100	٧
Maximum average forward rectified current at T <sub>C</sub> = 105 °C —	otal device	1	10		А
	per diode	I <sub>F(AV)</sub>	5.0		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	120		Α
Voltage rate of change		dV/dt	10 000		V/µs
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-65 to +150		°C

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	MBR1090CT	MBR10100CT	UNIT
Maximum instantaneous forward voltage	I <sub>F</sub> = 5.0 A	T <sub>A</sub> = 125 °C	V <sub>F</sub> <sup>(1)</sup>	0.75		V
		T <sub>A</sub> = 25 °C		0.85		
Maximum reverse current per diode at working peak reverse voltage		T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	100		μA
		T <sub>A</sub> = 100 °C	'R (-)	6.0		mA

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

# **MBR1090CT, MBR10100CT**

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THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	L MBR1090CT MBR10100CT			
Typical thermal resistance per diode	$R_{ heta JC}$	4	°C/W		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	MBR10100CT-M3/4W	1.87	4W	50/tube	Tube	

## **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

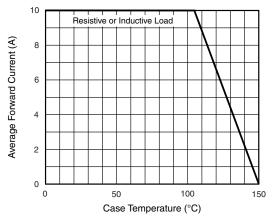


Fig. 1 - Forward Current Derating Curve

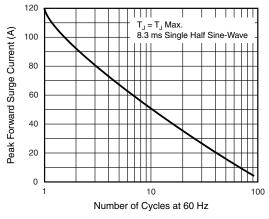


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

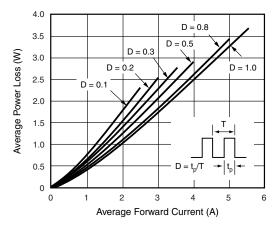


Fig. 3 - Forward Power Loss Characteristics Per Diode

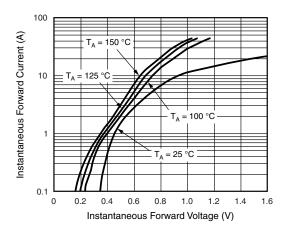


Fig. 4 - Typical Instantaneous Forward Characteristics Per Diode

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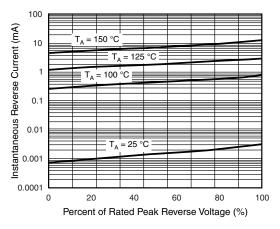


Fig. 5 - Typical Reverse Characteristics Per Diode

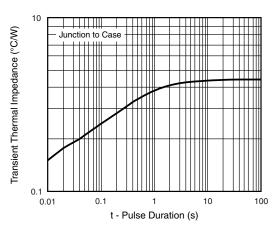


Fig. 7 - Typical Transient Thermal Impedance Per Diode

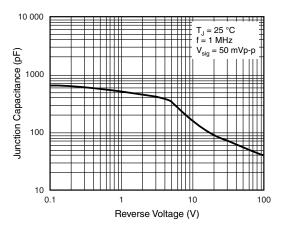
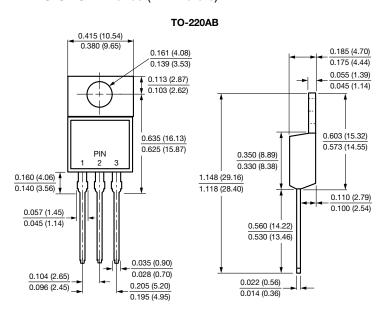


Fig. 6 - Typical Junction Capacitance Per Diode

#### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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